## NSN 5961-00-479-1454

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-479-1454 **Inclosure Material:** Metal **Overall Length:** 0.400 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches Thread Size: 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 breakover voltage, dc **Current Rating Per Characteristic:** 100.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Test Data Document:** 13499-353-6485 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: